



AMP1086 SOLID STATE HIGH POWER AMPLIFIER

FEATURES

- Class AB linear GaN design
- Instantaneous wide bandwidth
- Suitable for all modulations standards
- Small form factor & light weight
- Built-in protection circuits
- High reliability and ruggedness

ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	2.0 - 6.5 GHz	
Power Output CW	250 Watt Min	3dB lower @ 6.0 - 6.5GHz
Power Gain	54 dB Min	
Power Gain Flatness	4.0 dB p-p Max	Constant input power
Input/Output Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	>30 dBc Typ	44dBm/Tone, $\Delta = 1$ MHz
Harmonics	>20 dBc Typ	At rated Pout
Non Harmonics Spurious	>60 dBc	
Operating Voltage	28 - 30 VDC	
Current Consumption	52 Amp Max	At rated Pout
Max Input Power	+8 dBm	Without damage
Load VSWR Protection	$\infty : 1$	
Turn On / Off Speed	5 μ Sec Max	

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +65 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non Condensing

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	250 x 200 x 27 mm	Excluding Connectors
Weight	2 Kg.	
RF Connectors In/Out	SMA / Type-N female	
DC Power / Interface Connector	Hybrid 9-Pin D-Sub	9W4
Cooling	External Heatsink	Forced air required

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D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	FWD	OPTION 101 - Forward power detect
2	VVA	OPTION 103 - Variable Voltage Attenuator
3	CURRENT SENSOR	$I_p @ 20mV/100mA$ Typ
4	TEMP SENSOR	$V_T @ 10mV/^{\circ}C + 500mV$ Typ
5	SHUTDOWN	TTL
A1, A2	VDD	28VDC
A3, A4	GND	Ground

OUTLINE DRAWING

